S1F77310M0A



Power Bus Switch IC 1 to 1 Bus Switch

OVERVIEW

The S1F77310 series is the bus switch suitable for USB applications. The adopted CMOS process technology characterizes the S1F77310 series by low power consumption. The compact PLP-8 adopted for the package enables the S1F77310 series to be mounted on high-density assemblies.

The built-in level shift circuit eliminates the need of external level shift circuitry for the input to this IC.

■ FEATURES

 $\begin{array}{lll} \bullet & \text{Input voltage range} & : 3.0 \text{V to } 3.6 \text{V} \\ \bullet & \text{Low-current consumption} & : 14 \mu \text{A (MAX)} \\ \bullet & \text{Stand-by current} & : 1 \mu \text{A (MAX)} \\ \bullet & \text{Bus switch ON resistance} & : 5.3 \Omega \text{ (typ)} \\ \bullet & \text{Bus switch OFF capacitance} & : 1.7 \text{pF (typ)} \\ \end{array}$

APPLICATION

- · Mobile communication equipment (mobile phones, cordless phones, and wireless communication devices)
- · Mobile AV equipment
- · Home appliances
- · Cameras, and video equipment
- · Portable game devices
- Battery equipment

■ PACKAGE

• PLP-8 (1.60 mm x 1.60 mm)

■ APPLICATION CIRCUIT EXAMPLE

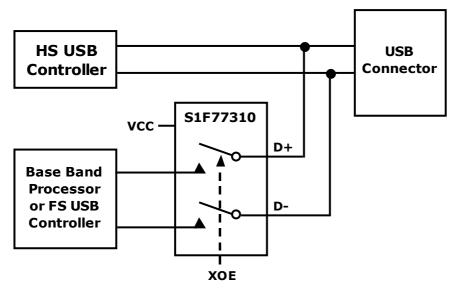


Fig.1 Application Circuit Example

■ PIN ASSIGNMENT

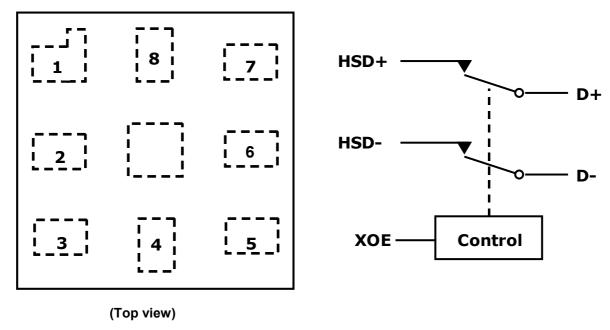


Fig.2 Pin Assignment

Fig.3 Bus switch symbol

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^{*} Central land area in this IC is not used. Do not mount any pin.

■ PIN DESCRIPTION

Pin No.	Pin Name	Pin Description
1	XOE	Bus switch enable input pin
2	HSD+	Data port (+)
3	D+	Data port (+)
4	GND	GND pin
5	D-	Data port (-)
6	HSD-	Data port (-)
7	(NC)	NC pin
8	Vcc	Power supply pin

■ TRUTH TABLE

XOE	Bus Switch status
HIGH	Disconnected
LOW	HSD+ =D+, HSD- =D-

■ BLOCK DIAGRAM

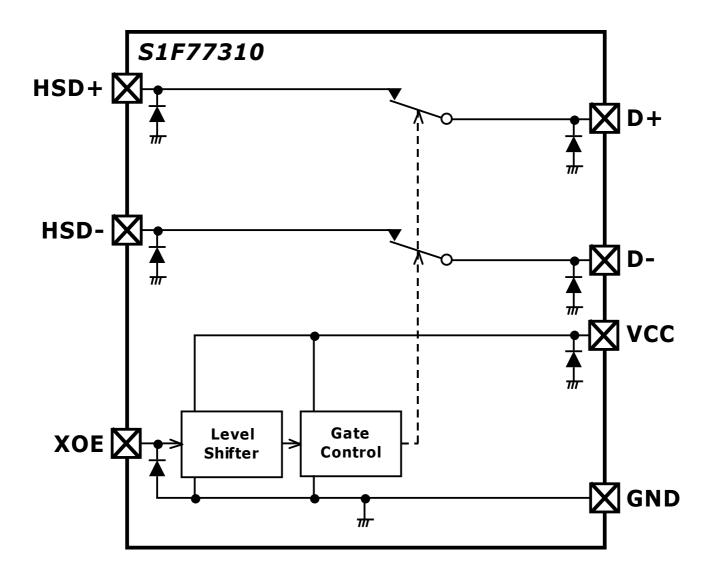


Fig.4 Block diagram

■ ELECTRICAL CHARACTERISTICS

■ ABSOLUTE MAXIMUM RATINGS

Iter	n	Symbol	Min.	Max.	Unit
Supply \	oltage	Vcc	-0.3	4.6	V
Input pin voltage	XOE	Vin	-0.3	7.0	V
Switch input voltage	HSD+,HSD-,D+,D-	Vsw	-0.3	7.0	V
Storage ter	nperature	Tstg	-65	150	°C

■ RECOMMENDED OPERATING CONDITIONS

Iter	n	Symbol	Min.	Max.	Unit
Supply v	oltage	Vcc	3.0	3.6	V
Input pin voltage XOE		Vin	0.0	5.5	V
Switch input voltage HSD+,HSD-,D+		Vsw	0.0	5.5	V
Operating te	mperature	Ta	-40	85	°C

■ DC ELECTRICAL CHARACTERISTICS

(Without protrusion:Ta= -40°C to 85°C)

Item	Symbol	Conditions	Vcc[V]	Min.	Тур.	Max.	Unit
Clamp diode voltage	Vık	IL=18mA	3.0			-1.2	V
High Level Input voltage	ViH		3.0 to 3.6	1.2			V
Low Level Input voltage	VIL		3.0 to 3.6			0.4	V
Input Leakage current	lin	0V≤VIN≤VCC	3.6	-1.0		1.0	μΑ
OFF Stage Leakage current	loz	0V≤Vsw≤Vcc	3.6	-1.0		1.0	μА
Power off Leakage current	loff	0V≤Vsw≤Vcc,Vcc=0V	0.0	-2.0		2.0	μΑ
(D+, D-)	Davi	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	2.0		5 0	0.0	0
Switch ON resistance	Ron	Vsw=0.4V,Ion, = -8mA	3.0		5.3	8.0	Ω
ΔON resistance	ΔRon	Vsw=0.4V,IoN, = -8mA	3.0		0.35		Ω
ON resistance flatness	RON(Flat)	0V≤Vsw≤1V,Ion= -8mA	3.0		2		Ω
Quiesent current	Icc	VIN=3.6V	3.6			1.0	μА
Current consumption	Ісст	VIN=0V,Vsw=2.6V	3.6			14.0	μΑ

^{*} Describe the value based on the USB full speed standard.

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■ AC ELECTRICAL CHARACTERISTICS

(Without protrusion:Ta= -40°C to 85°C)

		(Without protiduointia +0 0 to 00 0)					
Item	Symbol	Conditions	Vcc[V]	Min.	Тур.	Max.	Unit
Turn ON Time	ton	RL=50Ω, CL=5pF	3.0 to 3.6		5	20	μs
Turn OFF Time	t off	RL=50Ω, CL=5pF	3.0 to 3.6		21	40	ns
Propagation Delay	t PD	RL=50Ω, CL=5pF	3.3		0.25		ns
OFF Isolation	OIRR	RL=50Ω, CL=0pF, f=240MHz	3.0 to 3.6		-35		dB
Crosstalk	Xtalk	RL=50Ω, f=240MHz	3.0 to 3.6		-40		dB
-3dB Bandwidth	BW	RL=50Ω, CL=0pF, f=240MHz	3.0 to 3.6		1000		MHz
Channel to Channel Skew	tsk(0)	RL=50Ω, CL=5pF	3.0 to 3.6		50		ps
Skew of Opposite	tsk(P)	RL=50Ω, CL=5pF	3.0 to 3.6		20		ps
Transitions of the Same							
Output							
Total Jitter	tj	RL=50Ω, CL=5pF, tR=tF=500ps at 480Mbps	3.0 to 3.6		200		ps

■ CAPACITANCE

(Without protrusion:Ta= -40°C to 85°C)

Item	Symbol	Conditions	Vcc[V]	Min.	Тур.	Max.	Unit
Control input pin capacitance	Cin	Vcc=0V, f=1MHz	0.0		7.0		pF
Bus switch ON capacitance	Con	VIN=0V,f=1MHz	3.3		3.7		pF
Bus switch OFF capacitance	Coff	Vcc=0V,f=1MHz	0.0		1.7		pF

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